

GOOD TAKE

SILICON PIN PHOTO DIODE

AT40S-PD-01

AT40S-PD-01

DATA SHEET

REV. : 1.0

DATE: 20-Apr.-2007

■ FEATURES:

- Fast Response Time.
- High Photo Sensitive.
- Small Junction Capacitance.
- Lead free product, in compliance with RoHS.

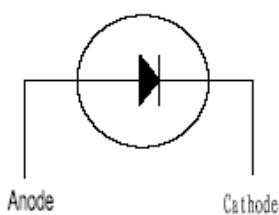
■ DESCRIPTIONS:

- AT40S-PD-01 is a high response speed and high sensitive silicon PIN photo diode with exceptionally stable characteristics and high illumination sensitivity.
- Molded in a compact surface-mountable package.

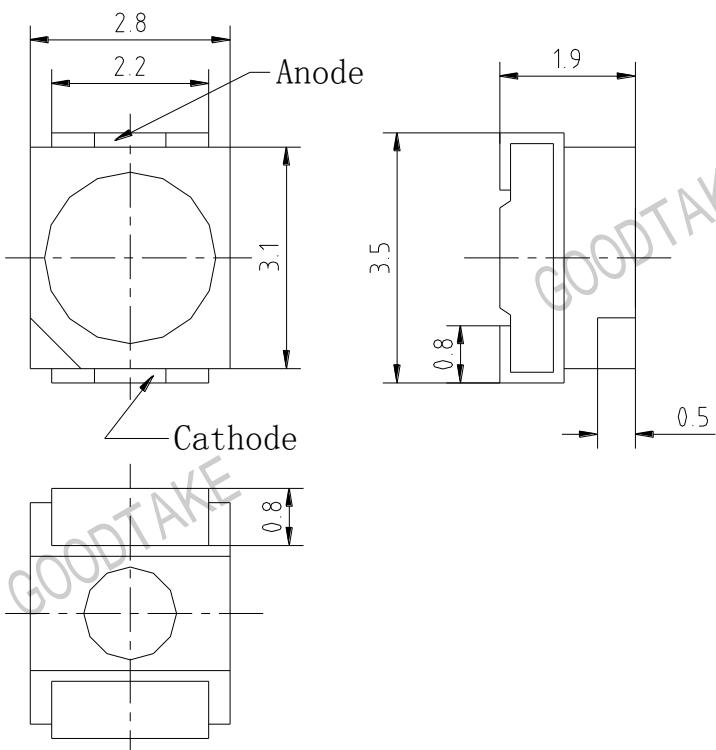
■ APPLICATIONS:

- Miniature switch.
- Counters and sorter.
- Position sensors.
- Infrared applied system.

■ INTERNAL CIRCUIT:



■ DIMENSIONS:



NOTE: All dimensions are in millimeter, tolerance is ± 0.2 unless otherwise noted.

■ ABSOLUTE MAXIMUM RATINGS AT Ta=25°C

Parameter	Symbol	Ratings	Unit
Power Dissipation	P _D	150	mW
Reverse Breakdown Voltage	V _{BR}	35	V
Operating Temperature	T _{opr}	-40~+85	°C
Storage Temperature	T _{stg}	-55~+100	°C
Soldering Temperature	T _{sol}	260°C for 6 sec Max	

■ TYPICAL ELECTRICAL & OPTICAL CHARACTERISTICS (Ta=25°C)

Parameter	Symbol	Min.	Type	Max.	Unit	Test Condition
Reverse Breakdown Voltage	V _(BR)	35			V	IR=100μA Ee=0mW/cm ²
Open-Circuit Voltage	V _{OOC}		0. 4		V	λp=940 nm Ee=5mW/cm ²
Short-Circuit current	I _{SC}		0. 8		μA	λp=875 nm Ee=1mW/cm ²
Rise Time	T _r		6		nS	V _R =5V R _L =1000Ω
Fall Time	T _f		6		nS	
Dark Current	I _D			10	nA	VR=10V Ee=0mW/cm ²
Light Current	I _L		1. 6		μA	λp=875 nm VR=5V Ee=1mW/cm ²
Range Of Spectral Bandwidth	λ _{1/2}	700		1100	nm	
Peak Wavelength of Sensitive	λ _p		940		nm	

■ RELIABILITY TEST ITEMS AND CONDITIONS:

NO	Item	Test Conditions	Test Hours/Cycle	Sample Quantity	Test Result
1	Solder Heat	TEMP: $270^{\circ}\text{C} \pm 3^{\circ}\text{C}$	10 SEC	11 pcs	0 DEFECT
2	Temperature Cycle	H: $+85^{\circ}\text{C}$ 60min ↓ L: -25°C 60min	16 cycles	22 pcs	0 DEFECT
3	Thermal Shock	H: $+85^{\circ}\text{C}$ 30min ↓ L: -25°C 30min	10 cycles	11 pcs	0 DEFECT
4	High Temperature Storage	TEMP: $+85^{\circ}\text{C}$	1000 HRS	22 pcs	0 DEFECT
5	Low Temperature Storage	TEMP: -25°C	1000 HRS	22 pcs	0 DEFECT
6	High Temperature High Humidity Storage	85°C/93% RH	1000HRS	22 pcs	0 DEFECT

■ TYPICAL ELECTRO-OPTICAL CHARACTERISTICS CURVES:

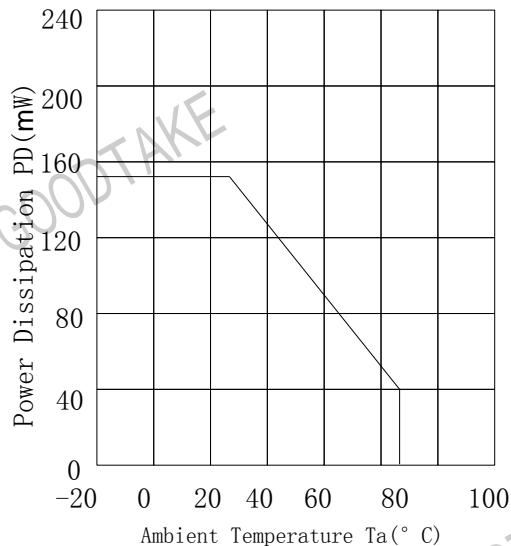


Fig. 1 Power Dissipation vs
Ambient Temperation

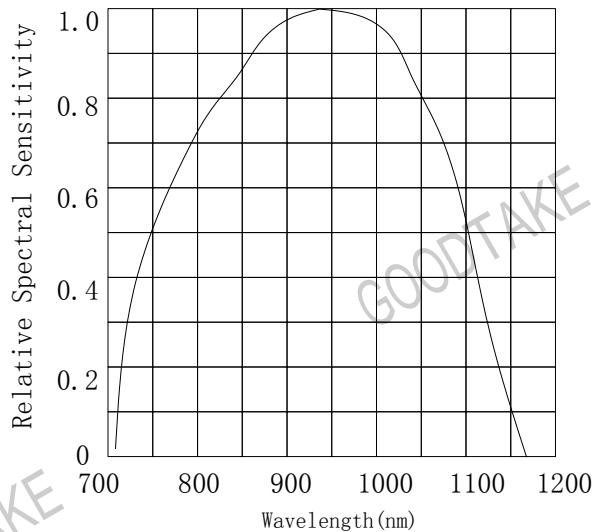


FIG. 2 Spectral Sensitivity

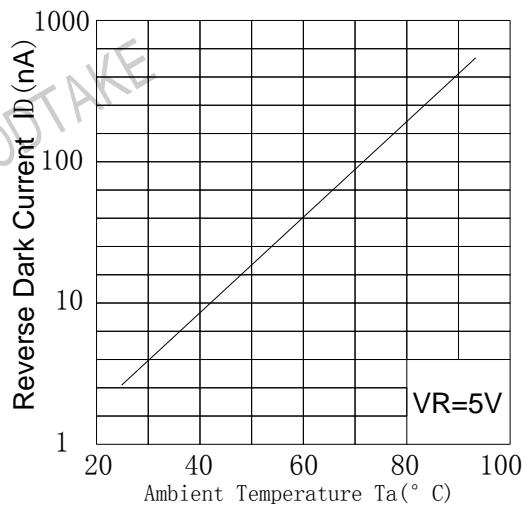


Fig. 3 Dark Current vs
Ambient Temperation

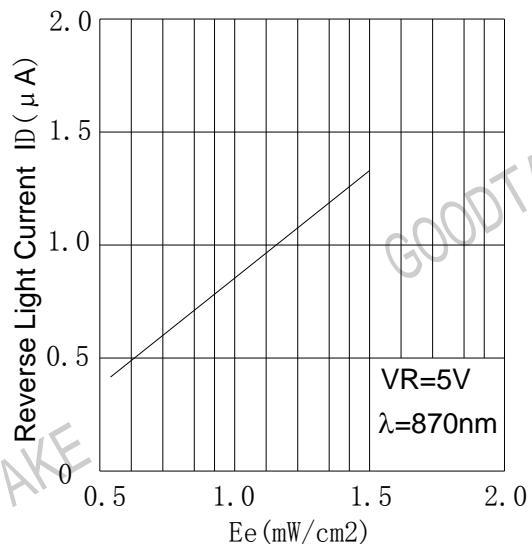


Fig. 4 Reverse Light Current vs
Ambient Temperation